

Thyristor High Voltage, Phase Control SCR, 50 A



PRIMARY CHARACTERISTICS				
I _{T(AV)}	50 A			
V _{DRM} /V _{RRM}	1200 V			
V _{TM} (typ.)	1.2 V			
I _{GT} (typ.)	45 mA			
T _J max.	150 °C			
Package	TO-247AD 3L			
Circuit configuration	Single SCR			

FEATURES

- AEC-Q101 qualified, meets JESD 201 class 1A whisker test
- Flexible solution for reliable AC power rectification



- Easy control peak current at charger power up to reduce passive / electromechanical components
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- On-board and off-board EV / HEV battery chargers
- Renewable energy inverters

DESCRIPTION

The VS-50TPS12 high voltage series of silicon controlled rectifiers are specifically designed for medium power switching, and phase control applications.

MAJOR RATINGS AND CHARACTERISTICS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Peak repetitive reverse voltage	V _{RRM} / V _{DRM}		1200	V	
On-state voltage	V _T	50 A, T _J = 125 °C	1.2	V	
Average rectified forward current	I _{T(AV)}		50		
Maximum continuous RMS on-state current	I _{RMS}		79	Α	
Non-repetitive peak surge current	I _{TSM}		630		
Maximum rate of rise	dv/dt		1000	V/µs	
Operating junction and storage temperature range	T _J , T _{Stq}		-40 to +150	°C	

VOLTAGE RATINGS			
PART NUMBER	V _{RRM} / V _{DRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} / I _{DRM} AT 150 °C mA
VS-50TPS12LHM3	1200	1300	70



ABSOLUTE MAXIMUM RATING	S					
PARAMETER	SYMBOL	TEST CONDITIONS		TYP.	MAX.	UNITS
Maximum average on-state current	I _{T(AV)}	T _C = 112 °C, 180° conduction half sine v	vave	-	50	
Maximum continuous RMS on-state current as AC switch	I _{T(RMS)}			-	79	Α
Peak, one-cycle non-repetitive surge current	l	10 ms sine pulse, rated V _{RRM} applied		-	530	
reak, one-cycle non-repetitive surge current	I _{TSM}	10 ms sine pulse, no voltage reapplied	Initial $T_J = T_J$	-	630	
12t for fusing	I ² t	10 ms sine pulse, rated V _{RRM} applied	maximum	-	1405	A ² s
I ² t for fusing	I-L	10 ms sine pulse, no voltage reapplied		-	1986	A-5
$I^2\sqrt{t}$ for fusing	l²√t	$t = 0.1$ ms to 10 ms, no voltage reapplied, $T_J = 125$ °C		-	19 850	A²√s
Low level value of threshold voltage	V _{T(TO)1}	T 405 00		-	0.89	V
High level value of threshold voltage	V _{T(TO)2}			-	0.97	V
Low level value of on-state slope resistance	r _{t1}	T _J = 125 °C		-	6.77	0
High level value of on-state slope resistance	r _{t2}			-	6.32	mΩ
On-state voltage	V	50 A, T _J = 25 °C		1.2	1.32	V
On-State Voltage	V _T	100 A, T _J = 25 °C		1.4	1.6	V
Rate of rise of turned-on current	di/dt	T _J = 25 °C		-	150	A/µs
Holding current	I _H	Anode supply = 6 V, resistive load, T _J = 25 °C		-	300	
Latching current	ΙL			-	350	A
Deverse and direct leakage august	1 /1	T _J = 25 °C		-	0.05	mA
Reverse and direct leakage current	I _{RRM} /I _{DRM}	T _J = 150 °C		-	70	
Rate of rise of off-state voltage	dv/dt	$T_J = T_J$ maximum, linear to 80 % V_{DRM} ,	R_g -k = 100 Ω	-	1000	V/µs

TRIGGERING						
PARAMETER	SYMBOL		TEST CONDITIONS	TYP.	MAX.	UNITS
Peak gate power	P _{GM}	10 ma aina nula	se, no voltage reapplied	-	10	W
Average gate power	P _{G(AV)}	TO THS SITIE PUIS	se, no voltage reapplied	-	2.5	l vv
Peak gate current	I _{GM}			-	2.5	Α
Peak negative gate voltage	-V _{GM}			-	10	
		T _J = -40 °C	Anode supply = 6 V resistive load	-	1.6	V
Required DC gate voltage to trigger	V_{GT}	T _J = 25 °C		=	1.5]
		T _J = 150 °C		=	1	
		T _J = -40 °C		-	160	
Required DC gate to trigger	I_{GT}	T _J = 25 °C	Anode supply = 6 V resistive load	45	100	mA
		T _J = 150 °C		-	60	
DC gate voltage not to trigger	V_{GD}	T _J = 150 °C, V _{DRM} = rated value		-	0.2	V
DC gate current not to trigger	I_{GD}	$I_{\rm J} = 150^{\circ} \rm C, V_{\rm D}$	-	3	mA	

SWITCHING					
PARAMETER	SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS
Turn-on time	t _{gt}	$I_T = 50 \text{ A}, V_D = 50 \% V_{DRM}, I_{gt} = 300 \text{ mA}, T_J = 25 \text{ °C}$	1.5	ı	
Turn-off time	tq	$I_T = 50$ A, $V_D = 80$ % V_{DRM} , $dV/dt = 20$ V/µs, $t_p = 200$ µs $I_{gt} = 100$ mA, $dI/dt = 10$ A/µs, $V_R = 100$ V, $T_J = 150$ °C	92	-	μs



THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	TYP.	MAX.	UNITS	
Maximum junction and storage te	emperature range	T _J , T _{Stg}		-40	150	°C	
Maximum thermal resistance, junction to case		R_{thJC}		-	0.35		
Maximum thermal resistance, junction to ambient		R_{thJA}		-	40	°C/W	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.2	-		
Mounting torque	minimum			6	(5)	kgf · cm	
Modriting torque	maximum			12	(10)	(lbf · in)	
Marking device			Case style Super TO-247AD 3L	;	50TPS12L	Н	

△R _{thJ-HS} CONDUCTION PER JUNCTION											
DEVICE	S	SINE HALF-WAVE CONDUCTION				RECTANGULAR WAVE CONDUCTION				LINUTO	
DEVICE	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	UNITS
VS-50TPS12LHM3	0.143	0.166	0.208	0.299	0.490	0.099	0.168	0.223	0.311	0.494	°C/W

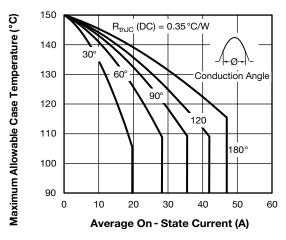


Fig. 1 - Current Rating Characteristics

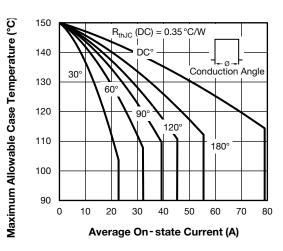


Fig. 2 - Current Rating Characteristics

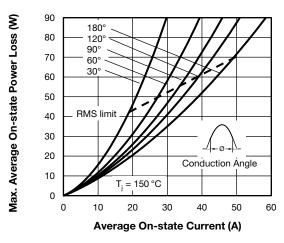


Fig. 3 - On-State Power Loss Characteristics

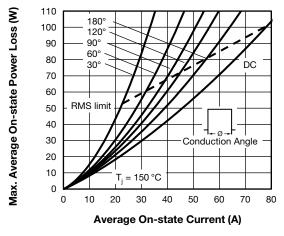


Fig. 4 - On-State Power Loss Characteristics

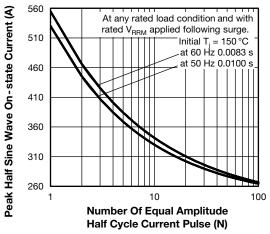


Fig. 5 - Maximum Non-Repetitive Surge Current

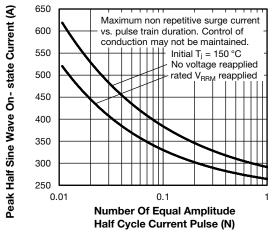


Fig. 6 - Maximum Non-Repetitive Surge Current

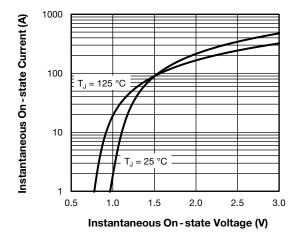


Fig. 7 - On-State Voltage Drop Characteristics

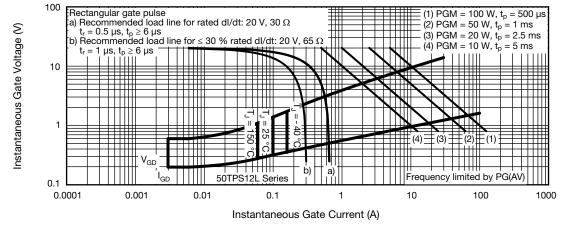


Fig. 8 - Gate Characteristics

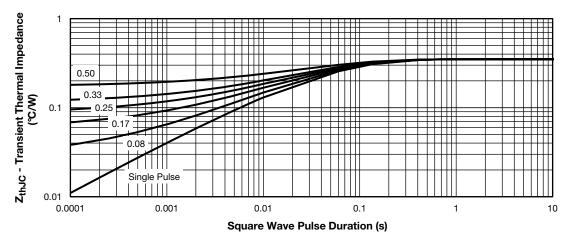
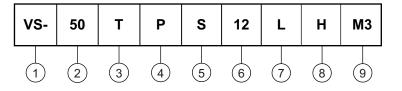


Fig. 9 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Dev	/ice	code	_



- 1 Vishay Semiconductors product
- 2 Current code (50 = 50 A)
- 3 Circuit configuration:
 - T = thyristor
- 4 P = TO-247AD package
- 5 Type of silicon:

S = standard recovery rectifier

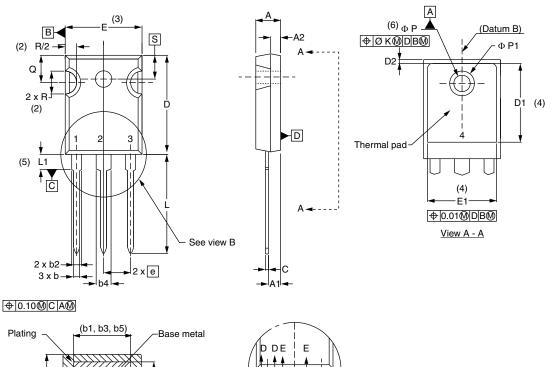
- Voltage code (12 = 1200 V)
- 7 Package L = long lead
- 11 450 0404 155
- 8 H = AEC-Q101 qualified
- 9 M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (example)						
PREFERRED P/N	RRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION					
VS-50TPS12LHM3	25	contact factory	Antistatic plastic tubes			

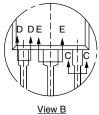
LINKS TO RELATED DOCUMENTS				
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626		
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007		

TO-247AD 3L

DIMENSIONS in millimeters and inches



Plating _	(b1, b3, b5)	-Base meta
(c)		c1
	(b, b2, b4) — (4)	
9	Section C - C, D - D	<u>, E - E</u>



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
С	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
Е	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46 BSC		0.215 BSC		
ØK	2.54		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØΡ	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		
	•	•	•		

INCHES

MILLIMETERS

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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NTE5592